

Chapter 8

Microwave Filters

SIMULATE A MICROSTRIP LOW PASS FILTER IN ADS USING DIFFERENT SIMULATION METHODS

Filter specs:

Cut-off frequency = 1.5 GHz (3 dB)

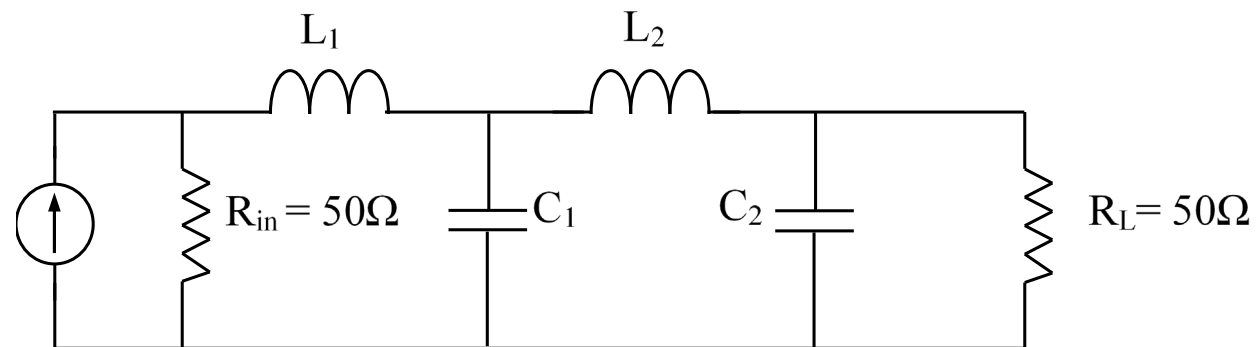
Rejection @ 3 GHz = 30 dB

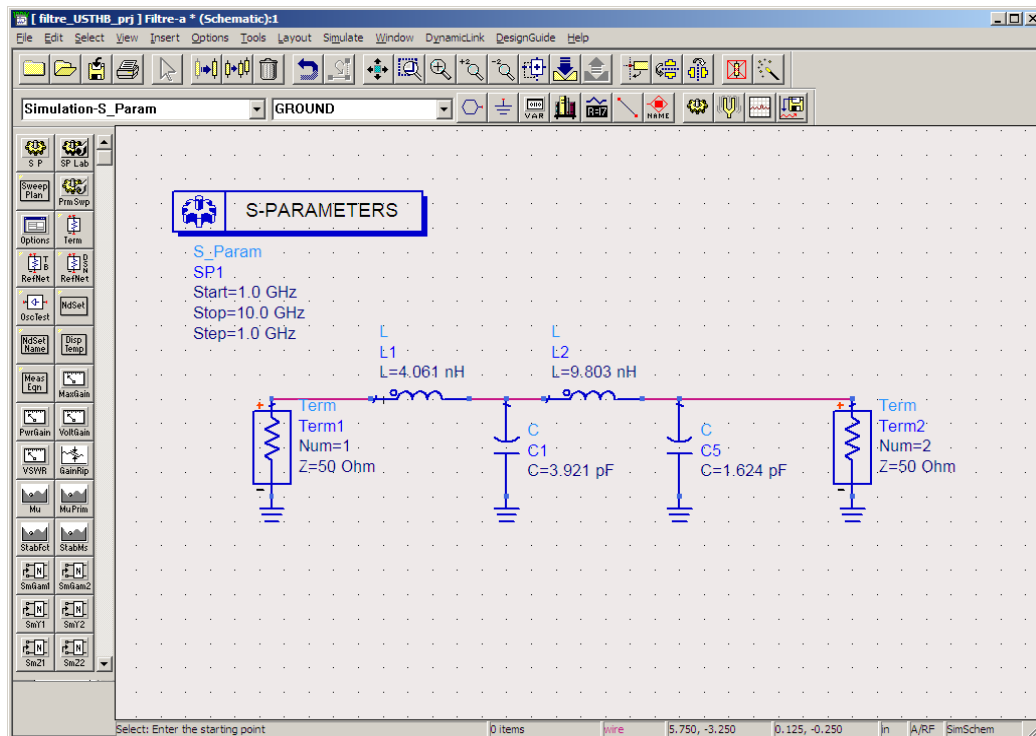
Substrate: FR4, $\epsilon_r = 4.2$ and $h = 1.5$ mm, $T = 38$ μm (fiber-glass)

Step 1 : Find the electric equivalent circuit:

Based on the specifications, we obtain $n = 4$ with

$$L_1 = 4.061 \text{ nH} \quad L_2 = 9.803 \text{ nH} \quad C_1 = 3.921 \text{ pF} \quad C_2 = 1.624 \text{ pF}$$





the specs :

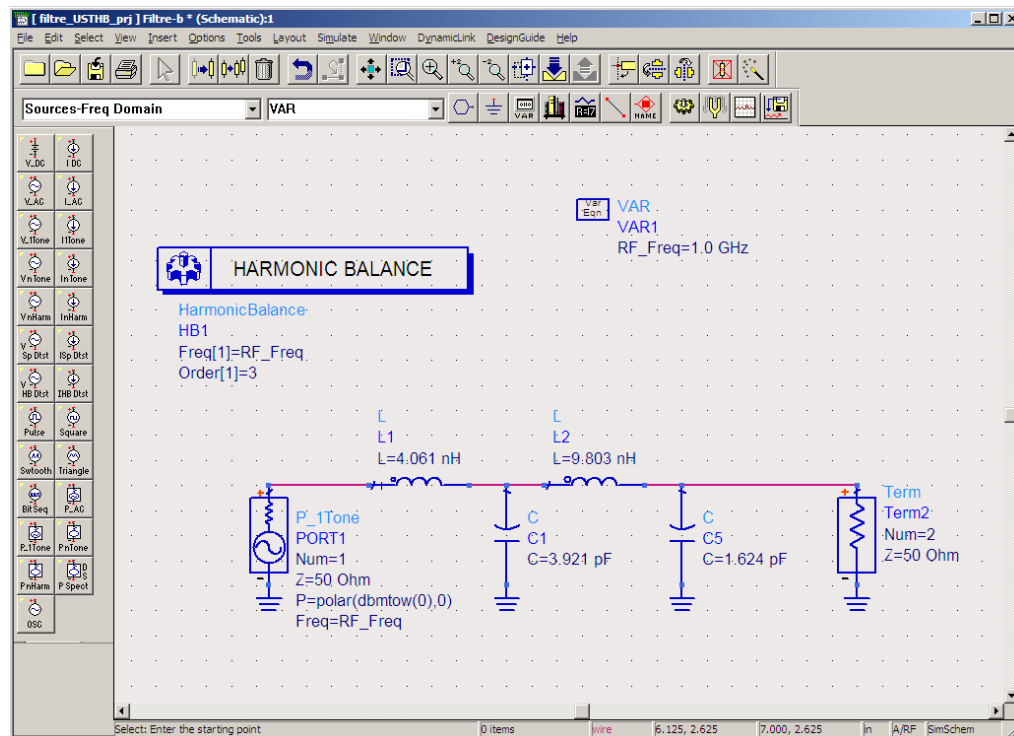
Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB

S-Parameters :

**The results are close
to the specs !**





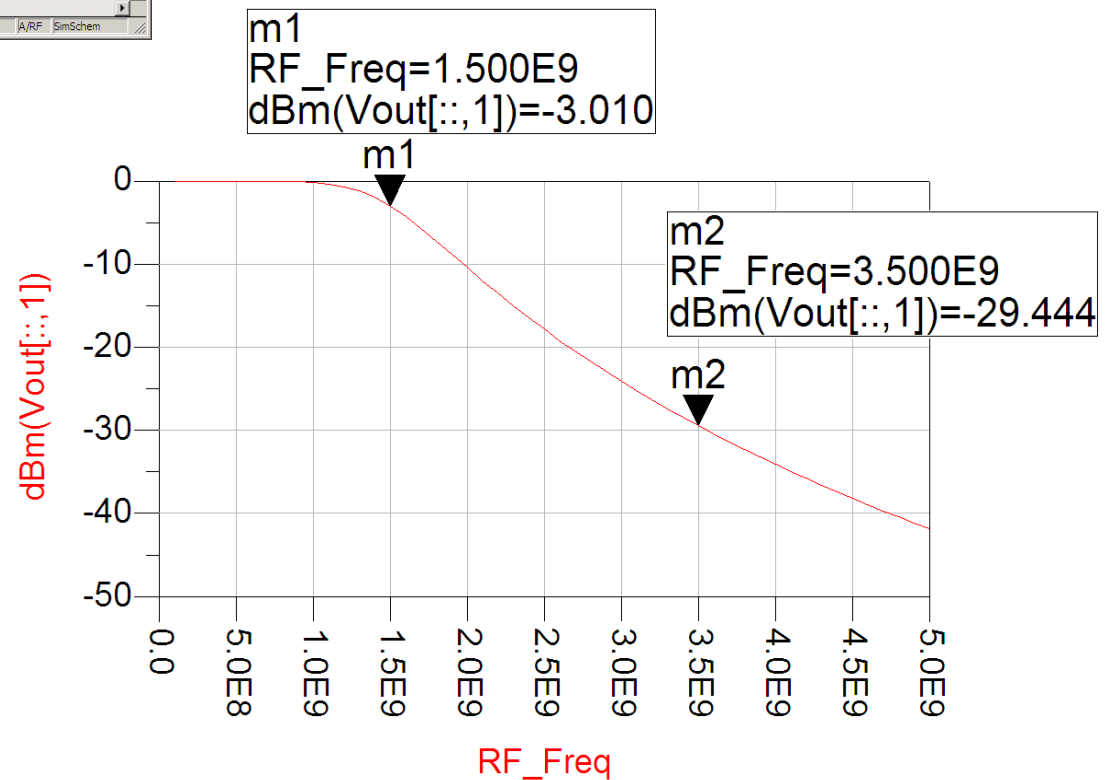
HB :

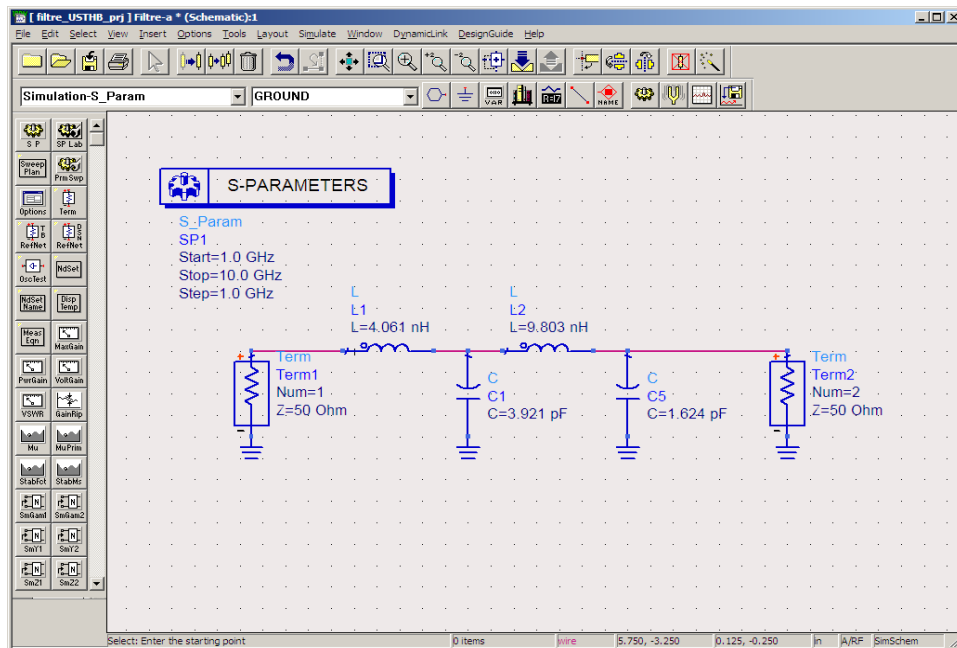
**The results are close
to the specs !**

the specs :

Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB





the specs :

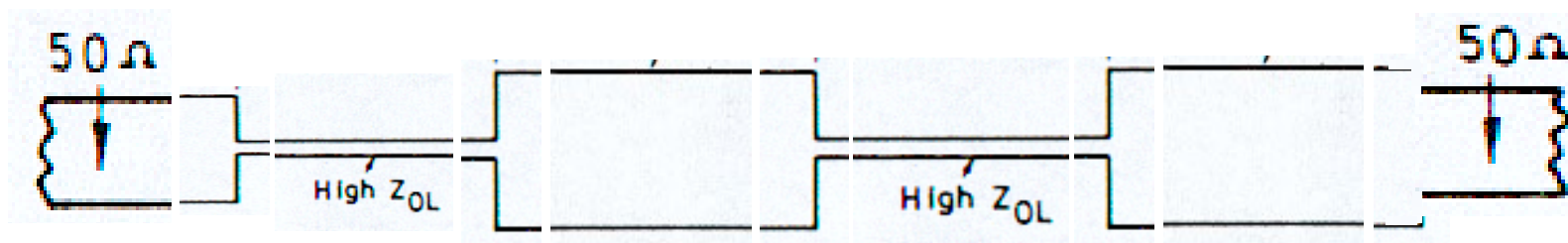
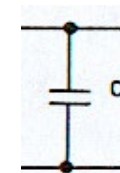
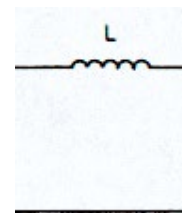
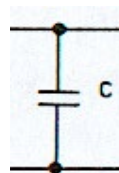
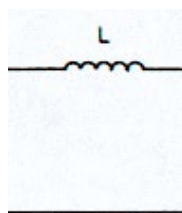
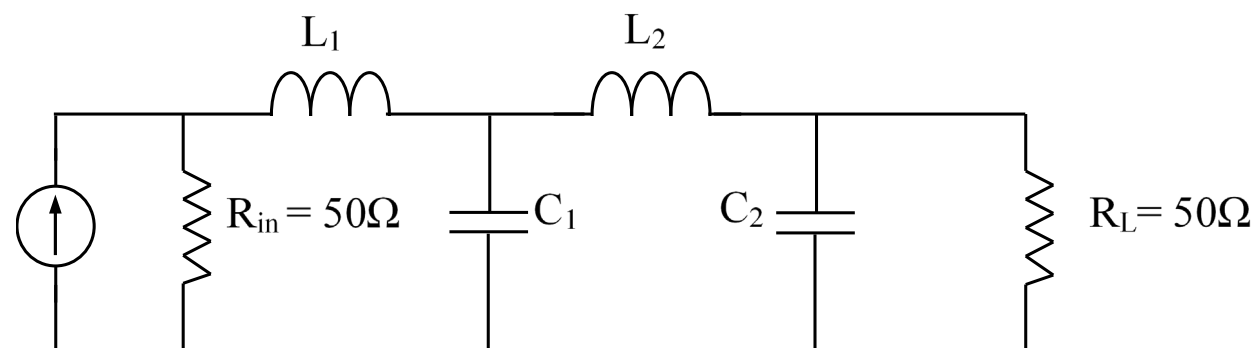
Cut-off frequency = 1.5 GHz (3 dB)

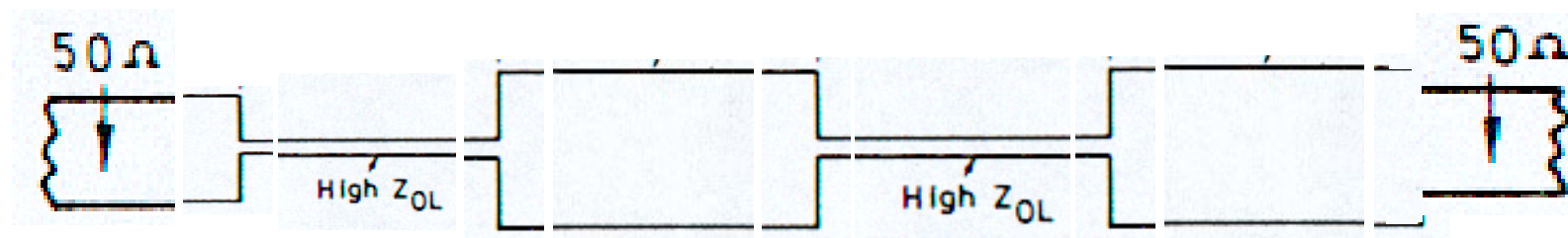
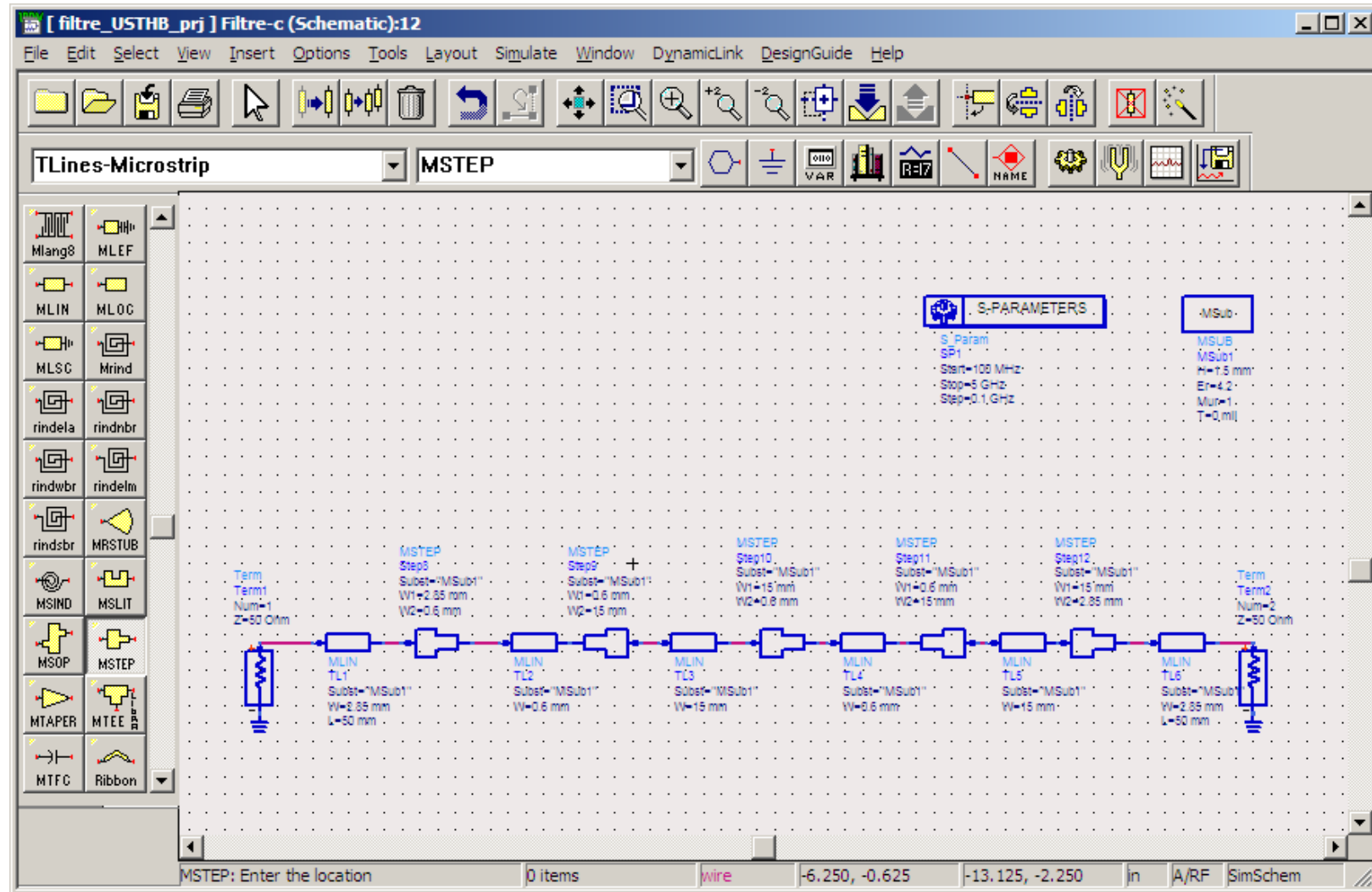
Rejection @ 3 GHz = 30 dB

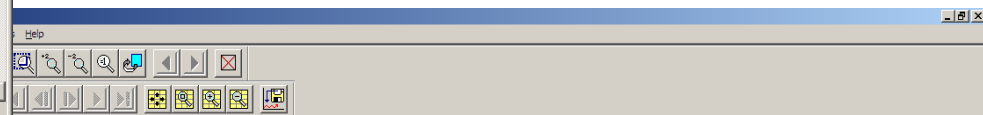
**Transform to planar transmission lines
(Microstrip lines)**

Convert the lumped elements to transmission lines

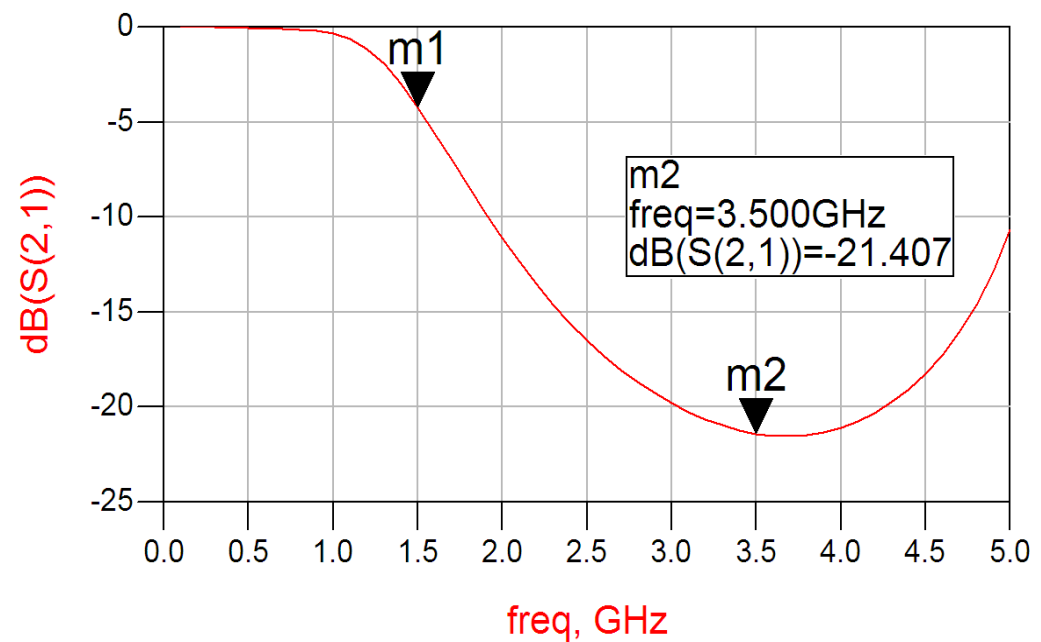
Capacitive lines	$Z_{0c} = 15 \Omega$	$w_C = 15 \text{ mm}$	Effective permittivity = 3.68
Reference	$Z_0 = 50 \Omega$	$w_o = 2.85 \text{ mm}$	Effective permittivity = 3.21
Inductive lines	$Z_{0L} = 110 \Omega$	$w_L = 0.6 \text{ mm}$	Effective permittivity = 2.83

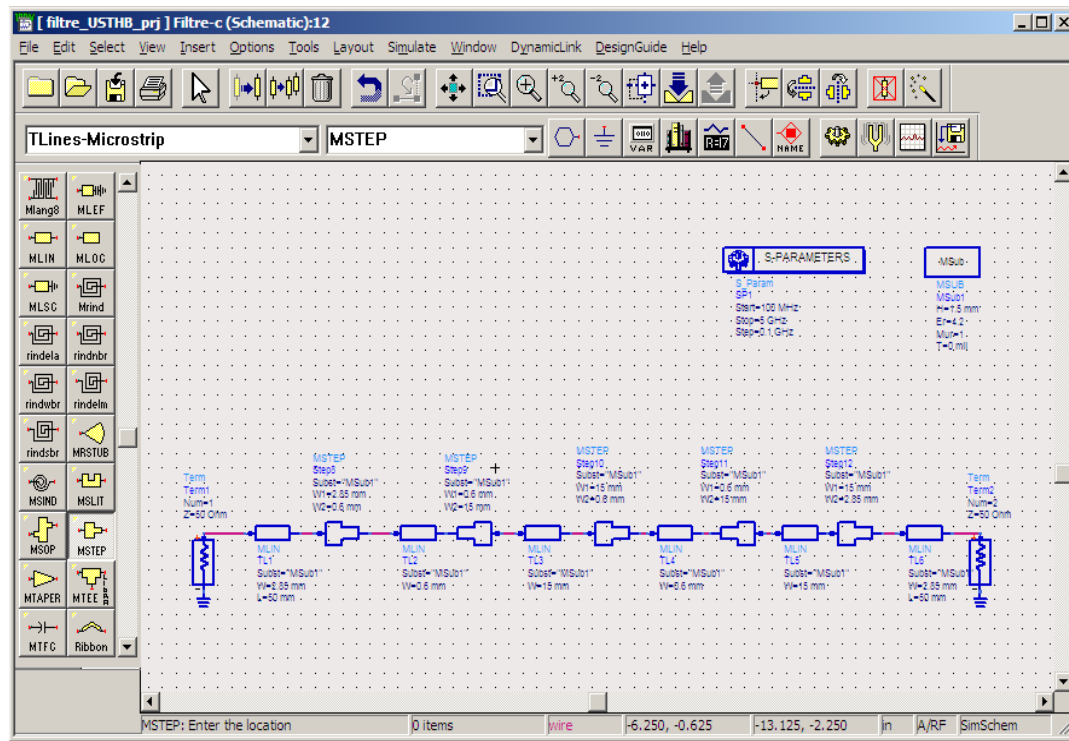






```
m1
freq=1.500GHz
dB(S(2,1))=-4.227
```





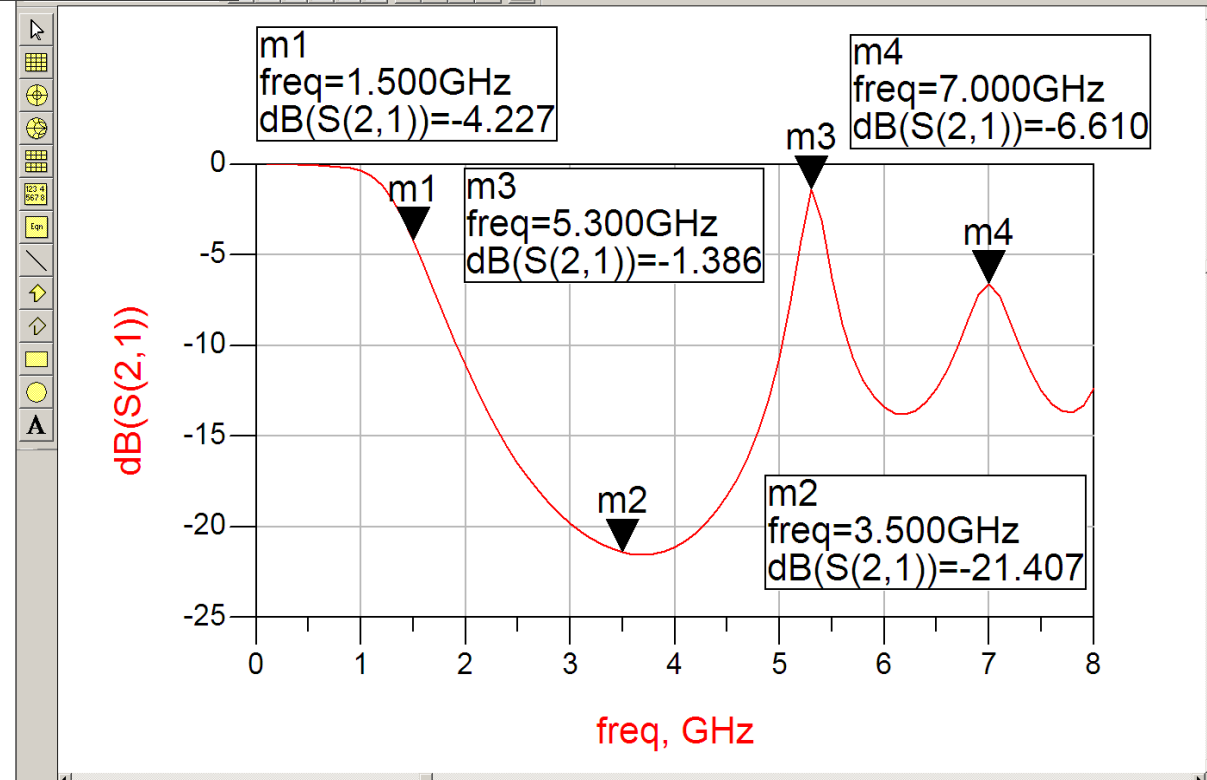
the specs :

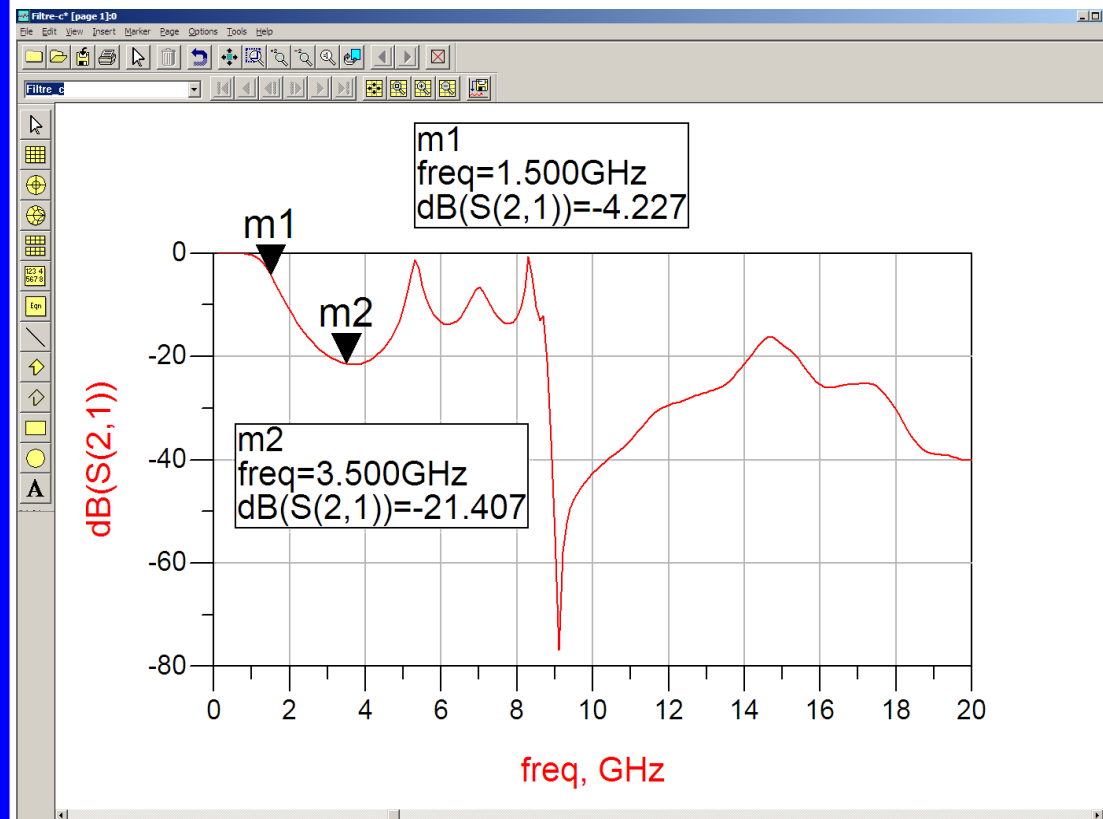
Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB

Re-simulate the filter by increasing the frequency (from 5 GHz to 8 GHz, same step-size: 0.1 GHz).

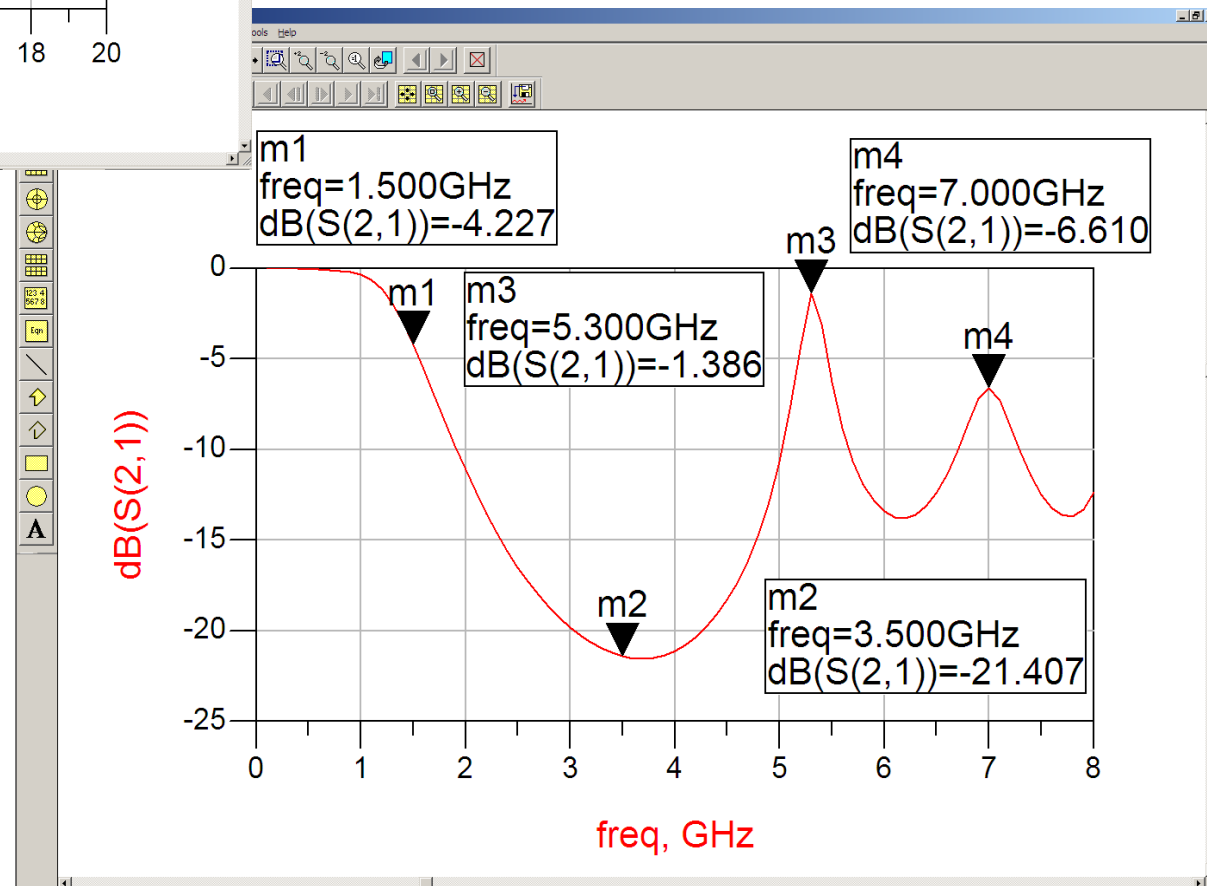
We see **two** peaks (-1.386 dB and -6.610 dB) at 5.3 GHz and 7 GHz, respectively.

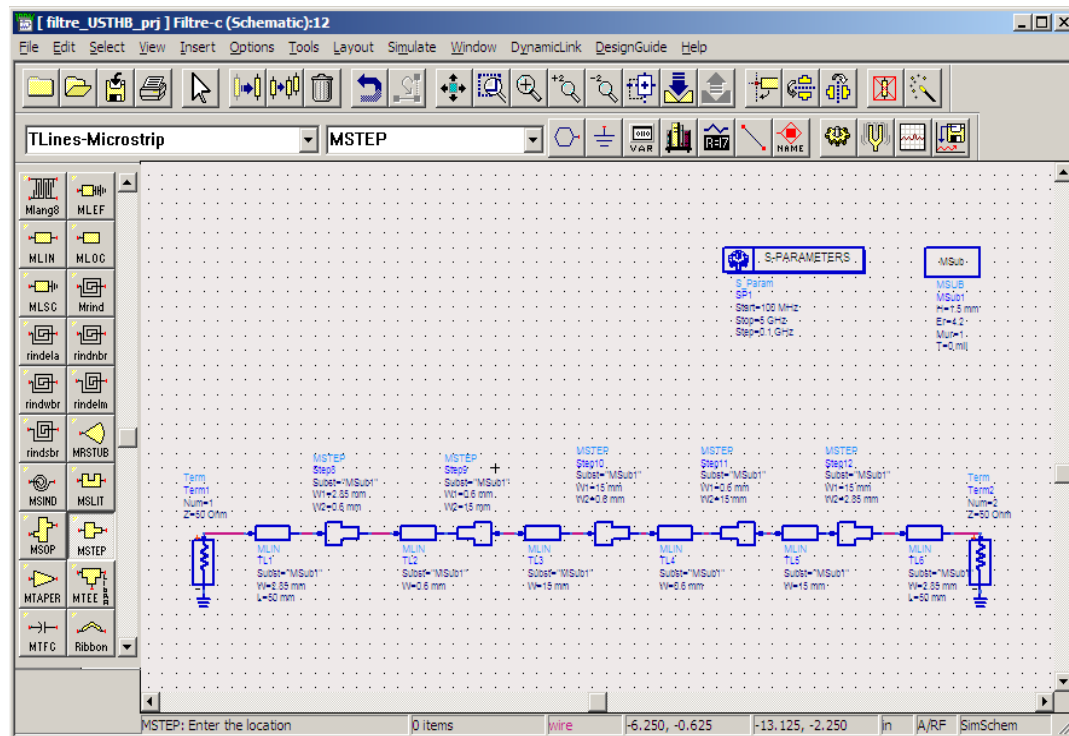




Re-simulate the filter by increasing the frequency (from 8 GHz to 20 GHz, same step-size: 0.1 GHz).

Conclusion ?





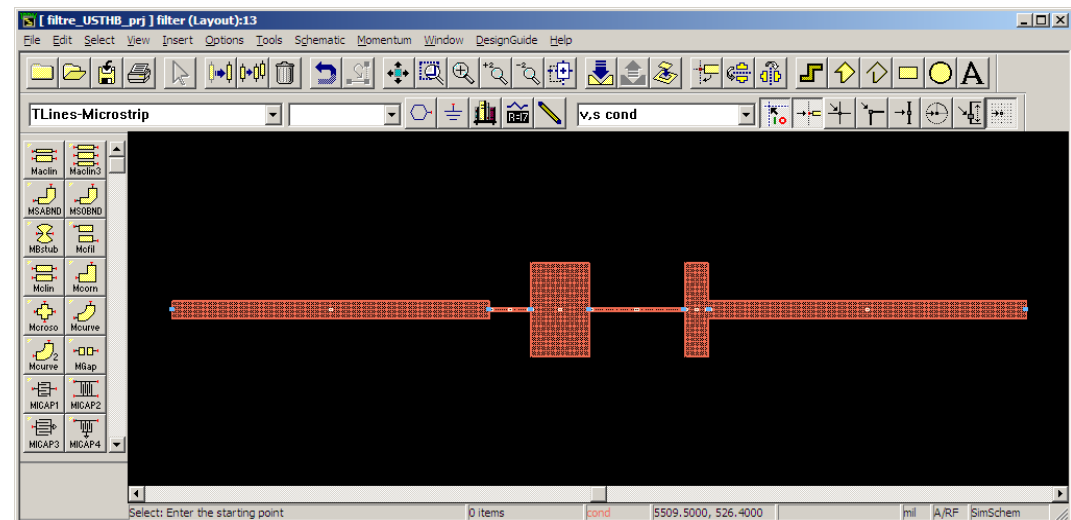
the specs :

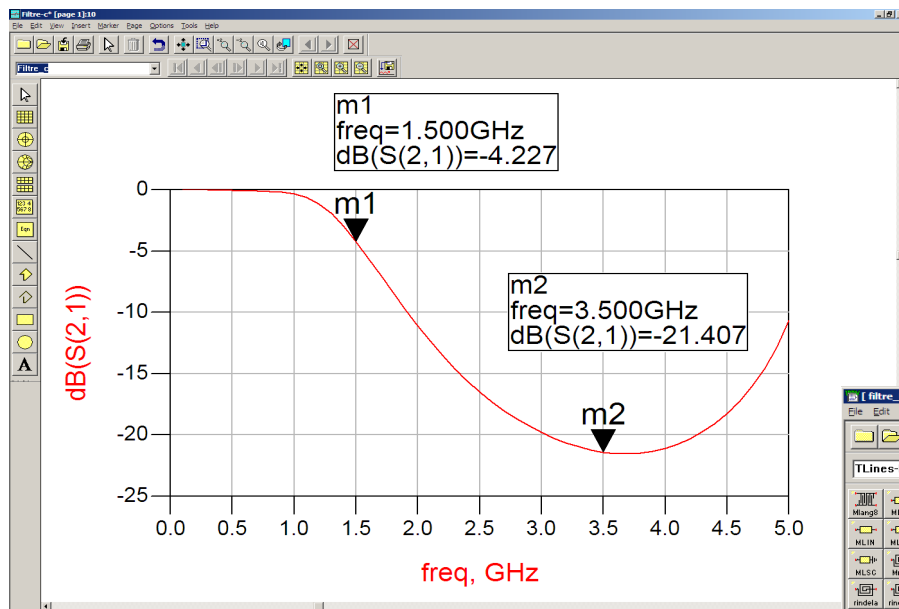
Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB

Simulation with the EM simulator: Momentum

Generate layout: from Schematic to Layout

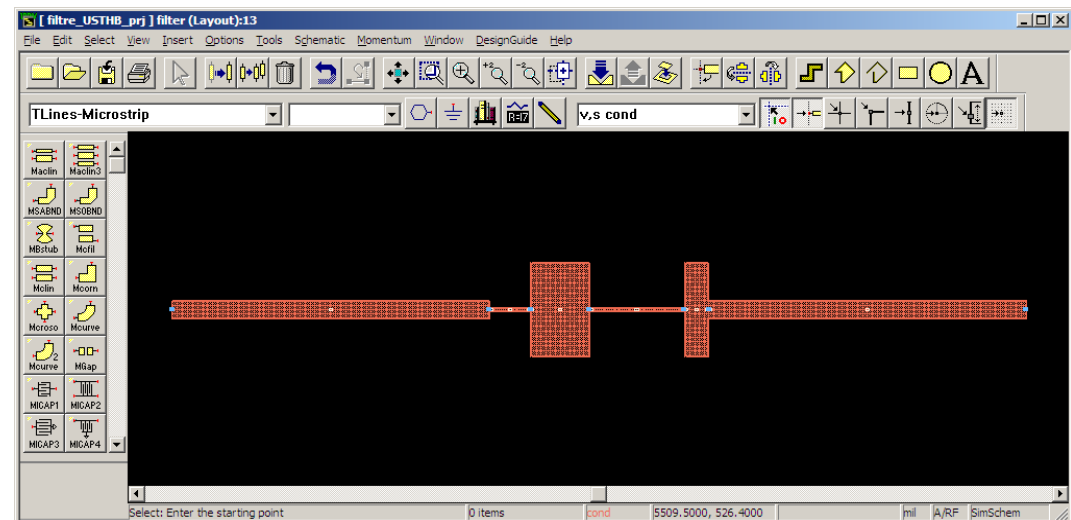
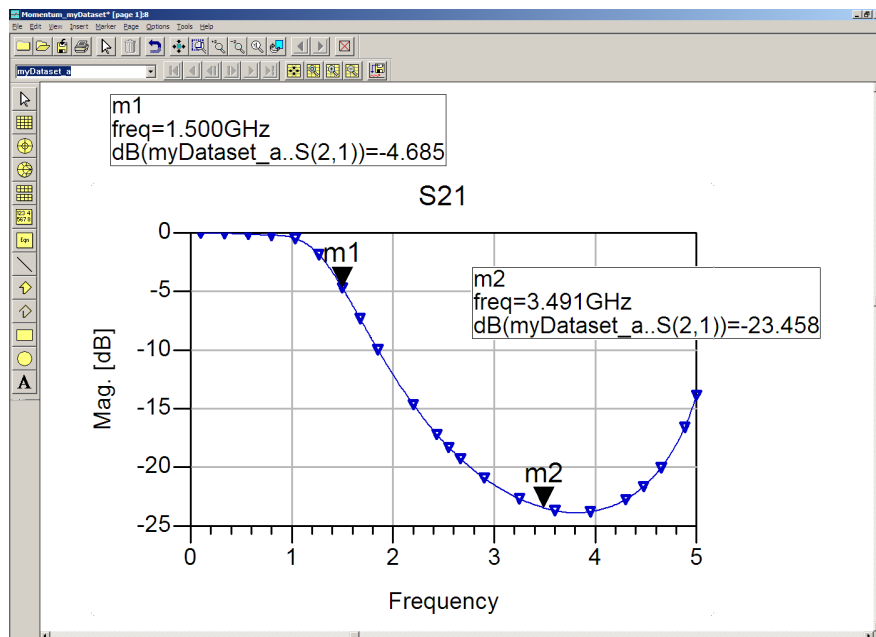
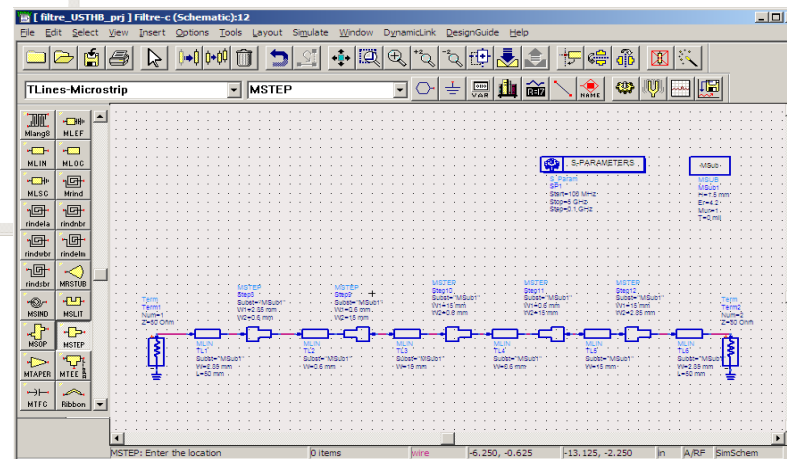




the specs :

Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB



WE SIMULATED A MICROSTRIP LOW PASS FILTER USING
THE **ADS** SOFTWARE AND FOUND SOME STRANGE BEHAVIOURS.

ADS-Momentum is a 2 D EM simulator.

**WHAT WOULD BE THE PERFORMANCE
IF
SIMULATED WITH ANOTHER SOFTWARE?**

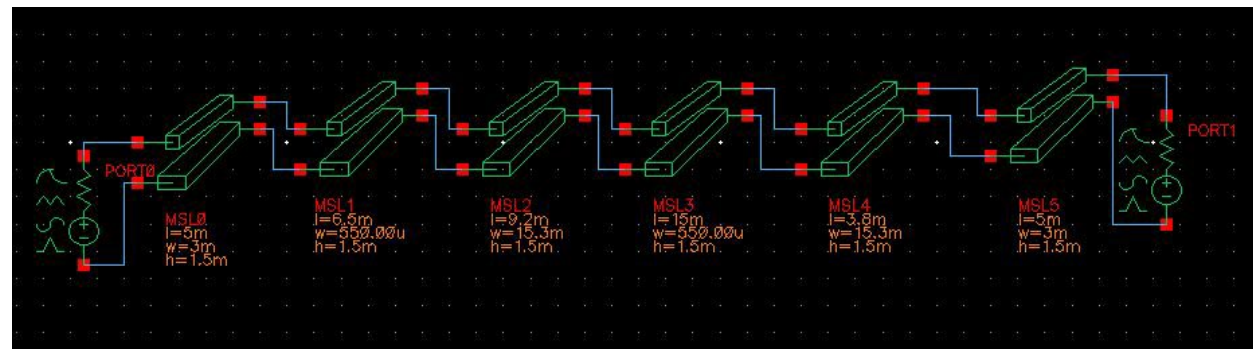
Filter specs:

Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB

Substrate: FR4, $\epsilon_r = 4.2$ and $h = 1.5$ mm, $T = 38$ μm (fiber-glass)

Simulations with Cadence



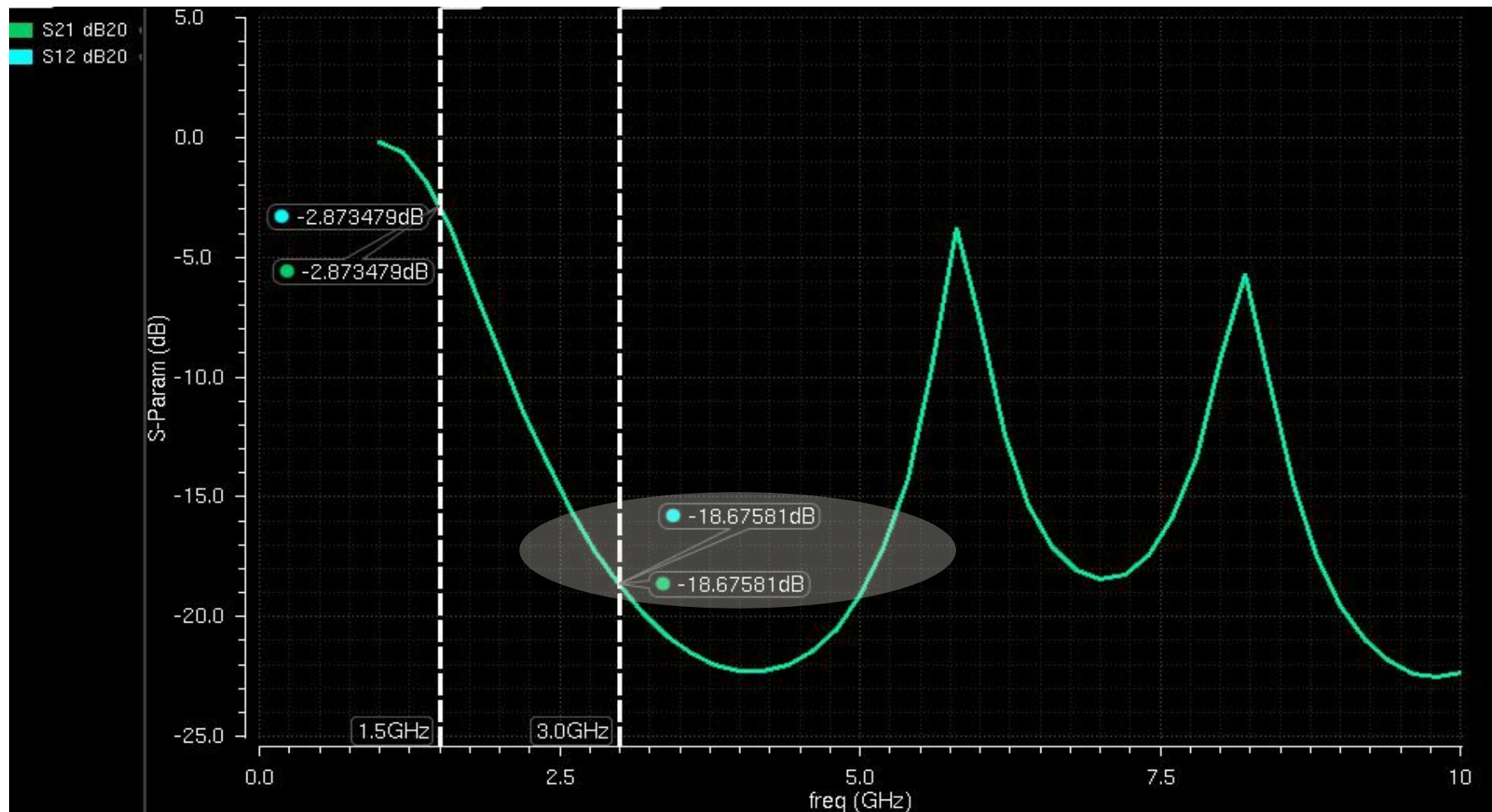
Note that Cadence uses the model for microstrip line
so doesn't need to define meshing.

Simulation results by Cadence
when mesh frequency is 10 GHz

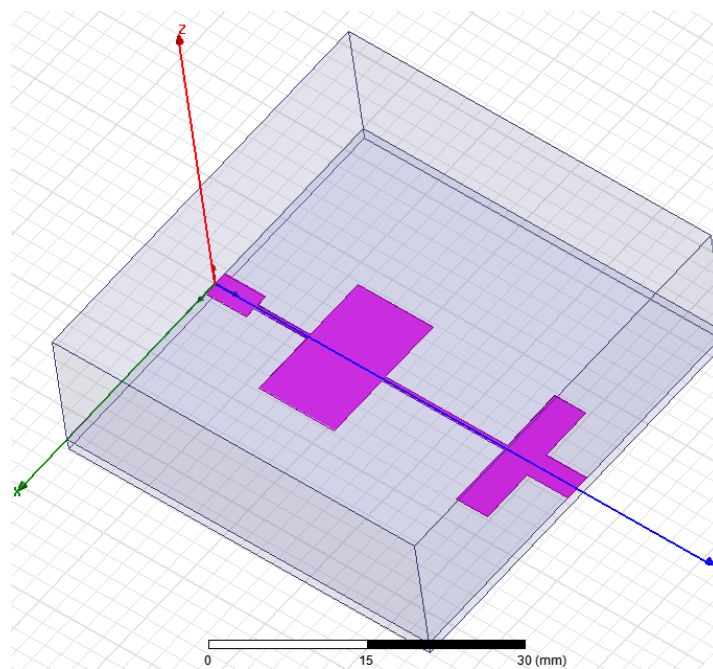
the specs :

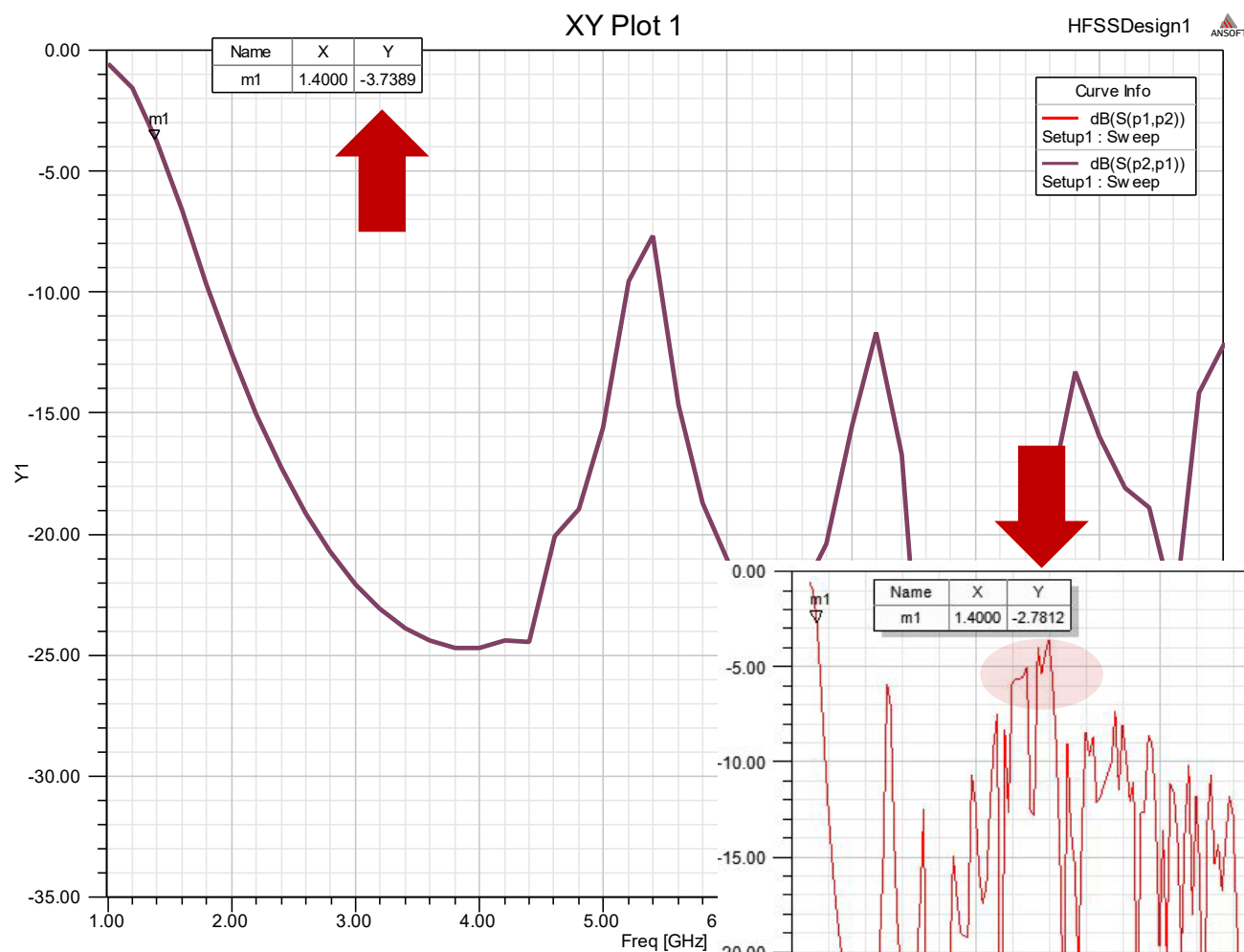
Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB



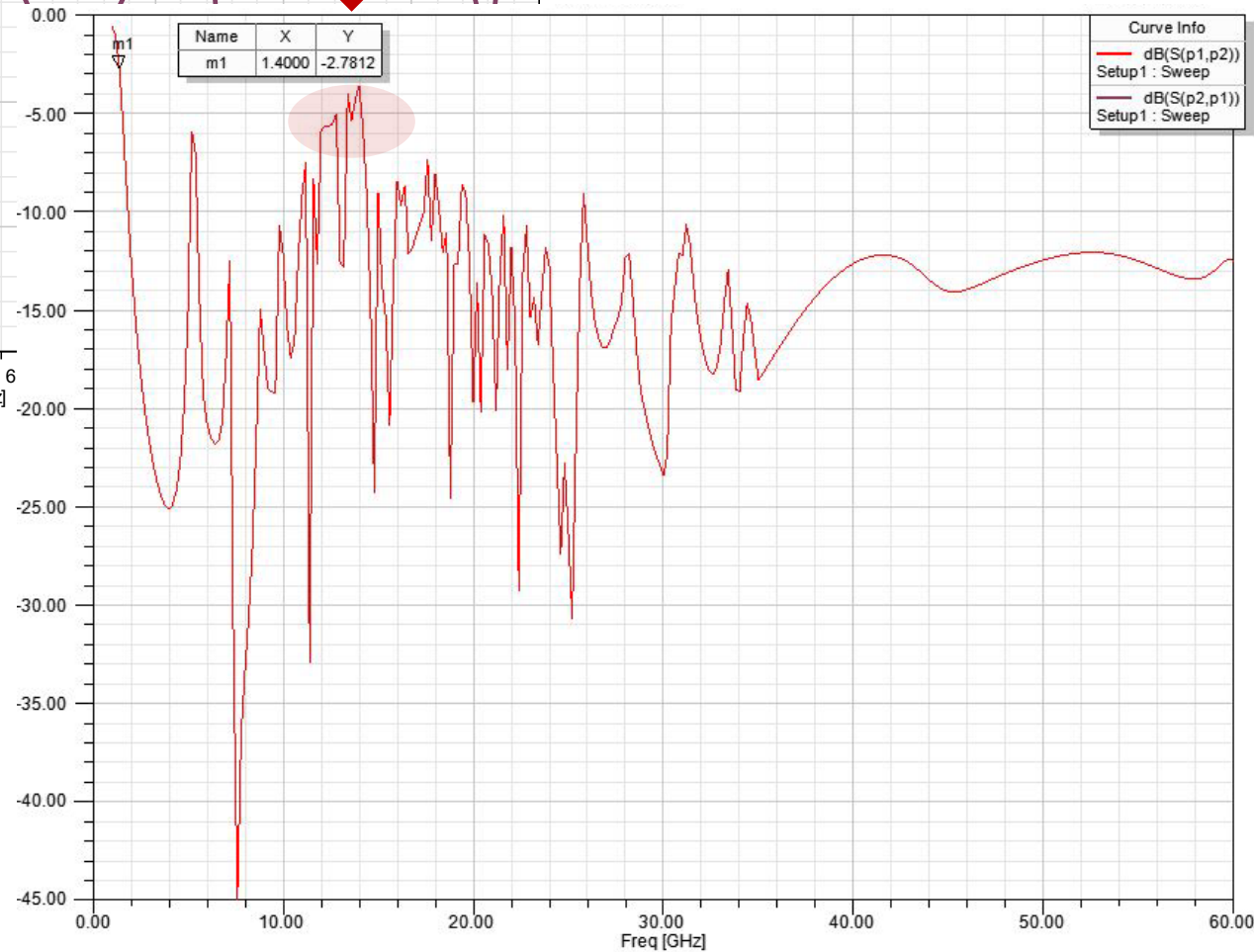
Simulations with HFSS 3D EM simulator



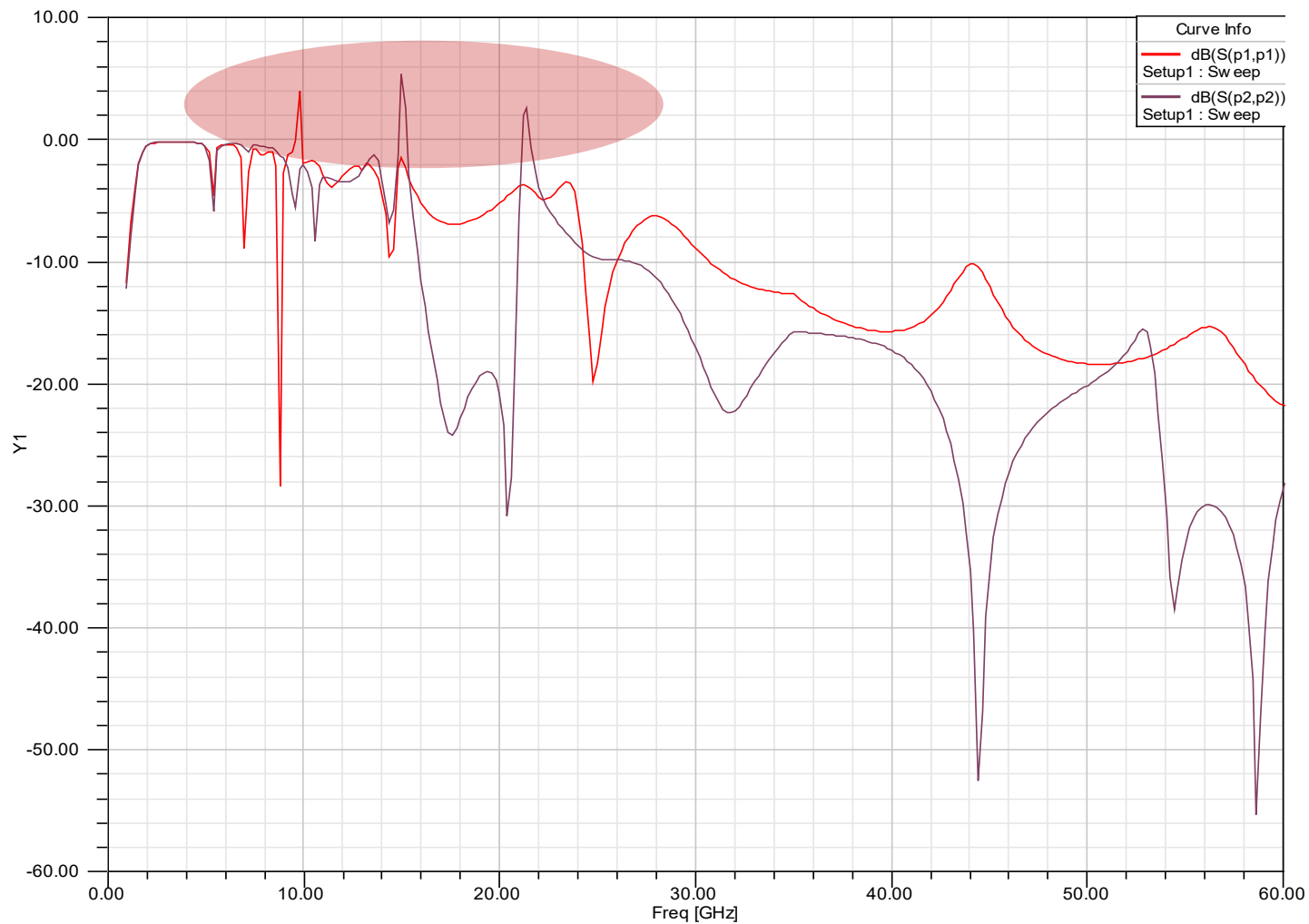


Simulation results by
HFSS when mesh
frequency is 10 GHz

Simulation results by
HFSS when mesh
frequency is 60 GHz



Furthermore, when we use the function “adaptive sweep frequency” in HFSS, we got



**WE SIMULATED A MICROSTRIP LOW PASS FILTER
USING DIFFERENT SOFTWARE AND STRANGE BEHAVIOURS ARE STILL THERE.**

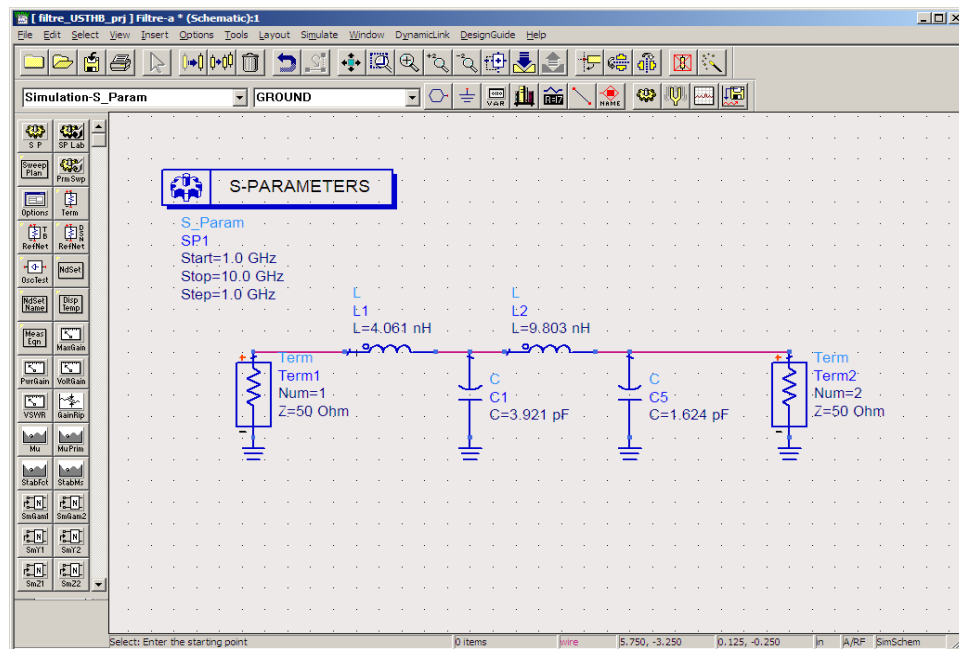
SO WE CANNOT TOTALLY BLAME THE SOFTWARE !

Filter specs:

Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB

Substrate: FR4, $\epsilon_r = 4.2$ and $h = 1.5$ mm, $T = 38$ μm (fiber-glass)



the specs :

Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB

Let us come back to the layout in ADS and check !

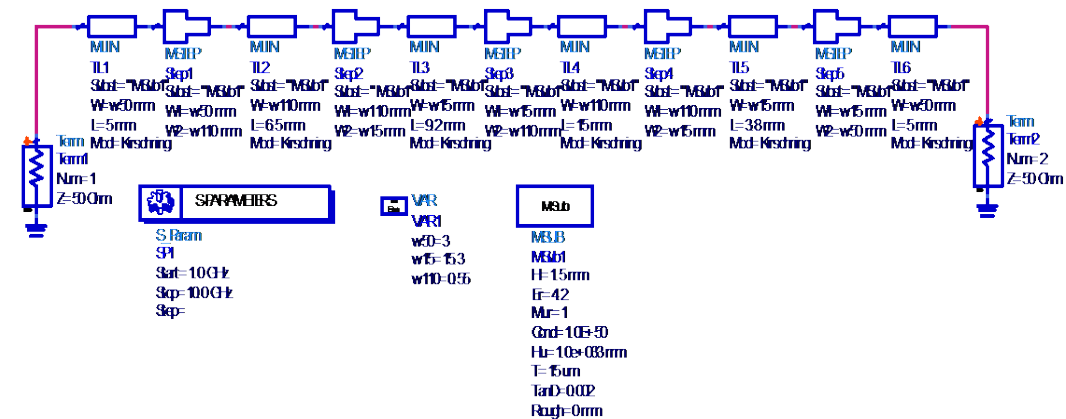
Convert the lumped elements to transmission lines

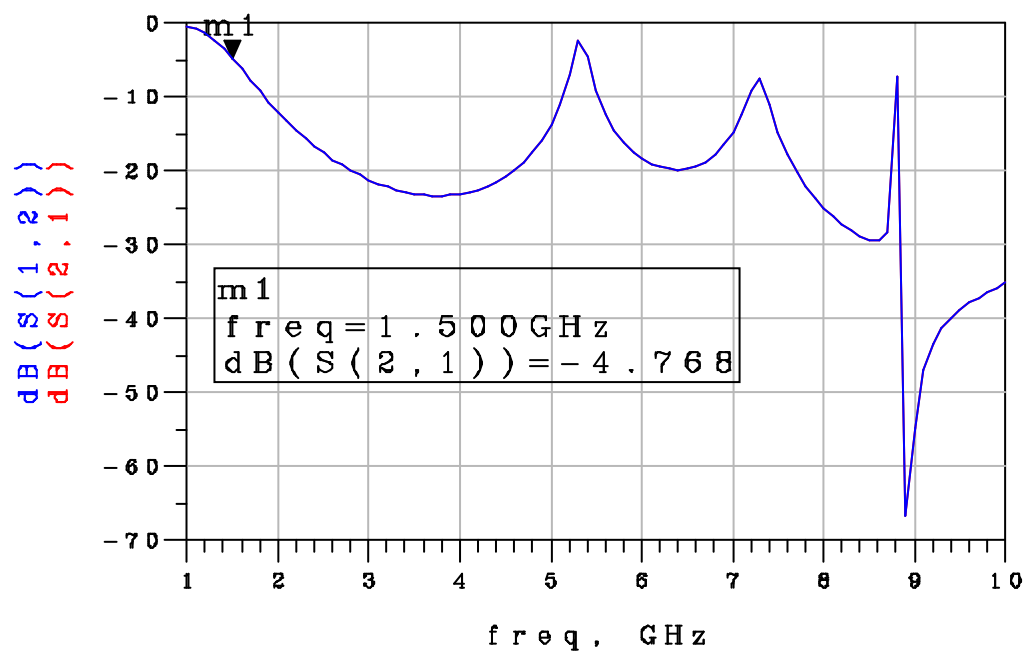
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Inductive lines	$Z_{0L} = 110 \Omega$	$w_L = 0.6 \text{ mm}$	Effective permittivity = 2.83

By assuming 15Ω for capacitive lines and 110Ω for inductive lines, we had

Freq (GHz)	W_{50} (mm)	W_{15} (mm)	W_{110} (mm)
1	2.96	15.13	0.53
3	2.97	15.26	0.53
10	3.19	16.11	0.58
25	3.98	17.52	1.00
60	4.61	17.88	1.75
100	4.78	17.9	2.09

We chose $W_{50}=3\text{mm}$, $W_{15}=15.3\text{mm}$
and $W_{110}=0.55\text{mm}$ and got the
following schematic:





the specs :

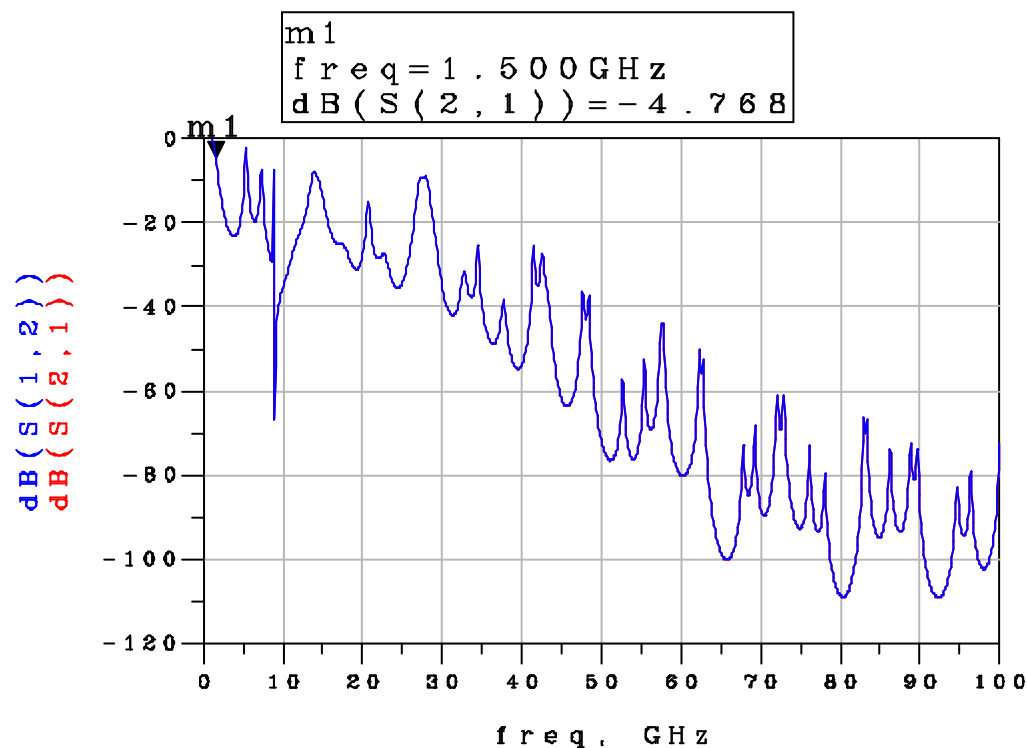
Cut-off frequency = 1.5 GHz (3 dB)

Rejection @ 3 GHz = 30 dB

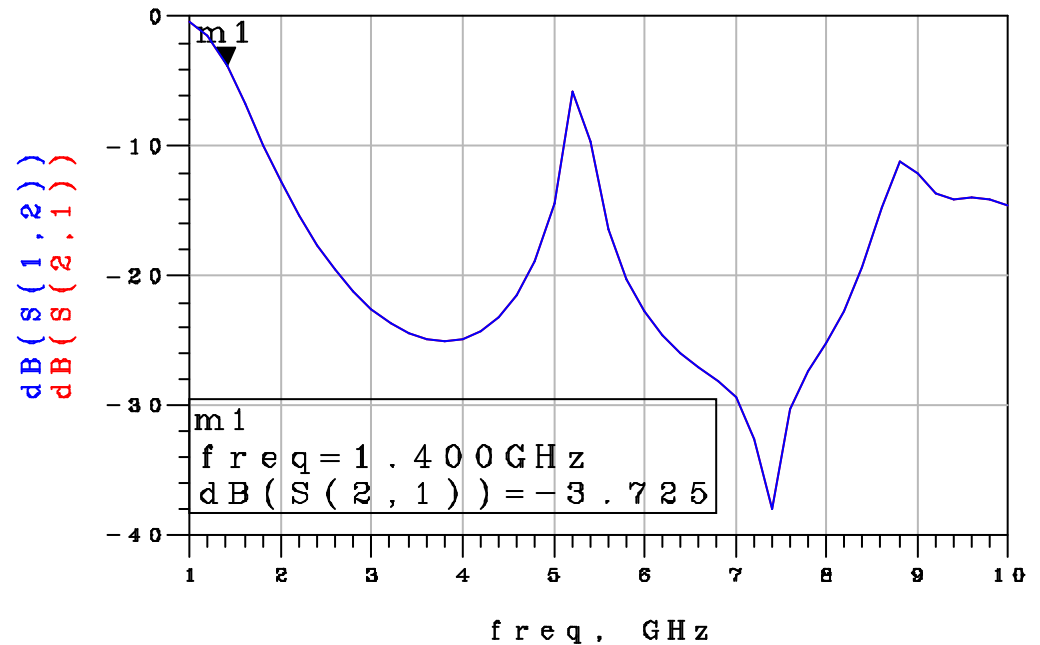
Up to 10 GHz

Fine !

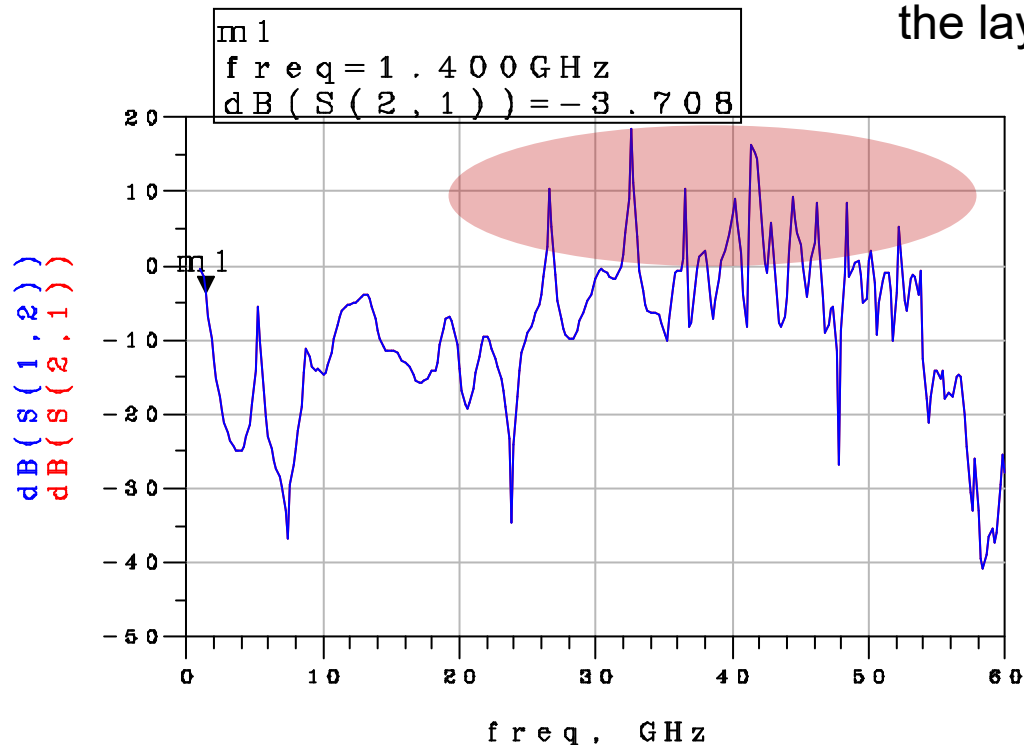
Up to 100 GHz



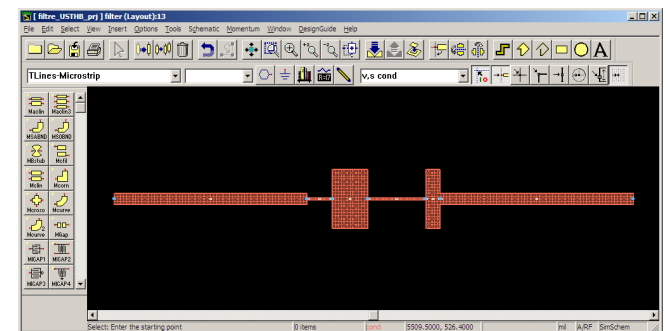
Simulation results by ADS
momentum when mesh density
is 40 per wavelength and mesh
frequency is 10 GHz



Now, let us check
the layout:



Simulation results by ADS
momentum when mesh density
is 30 per wavelength (to reduce
the simulation time) and mesh
frequency is 60 GHz.



Let us check to what is “behind the screen” in ADS.

Although we defined the mesh as fine as possible, the results are wrong at some frequencies. As seen from figure below, ADS itself has predicted the probability of wrong results in some simulations: higher order modes ?

```
Generating mesh at 60 GHz...  
Mesh generation finished  
S-parameter simulation  
Automatic selection: direct dense matrix solver  
Using multi-threading (4 threads)  
WARNING : S-parameter results show unphysical behavior for certain frequencies.  
Cause      : - inaccurate (high frequency) calibration ;  
              - electrically large via using lumped model ;  
              - higher order modes at the ports ;  
              - slot mode at coplanar ports ;  
              - grouped strip-slot ports ;  
              - mesh density is too coarse.
```

Let us come back to the table :

What is wrong ?

Freq (GHz)	W_{50} (mm)	W_{15} (mm)	W_{110} (mm)
1	2.96	15.13	0.53
3	2.97	15.26	0.53
10	3.19	16.11	0.58
25	3.98	17.52	1.00
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100	4.78	17.9	2.09

From the theory, the values of W (the width) for a constant impedance should be almost constant (at least for the lowest frequency portion of the electromagnetic spectrum, e.g., in the range 1-10 GHz).

Why ?

QUASI-TEM propagation mode properties as explained in class !!

Let us come back to the table :

What is wrong ?

Freq (GHz)	W_{50} (mm)	W_{15} (mm)	W_{110} (mm)
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100	4.78	17.9	2.09

In fact, the effective permittivity of a microstrip line is usually independent of frequency
(at least for the low frequencies portion of the microwave spectrum)

but we noticed here that for the substrate FR4 (**taken by default in ADS**), the effective permittivity and thus, the characteristics impedance is dependent on frequency.

→ dispersive fields are huge, increasing with the frequency.

A too thick substrate acts as a cavity

Therefore, we shouldn't expect realistic responses from microstrip filters at very wide band widths, especially for thick substrates.

Solution ?

Effective permittivity and width
for a 50 Ω impedance

Substrate, $\epsilon_r = 4.2$, $h = 1.5$ mm

Freq (GHz)	W_{50} (mm)	E_{eff}
1	2.96	3.21
3	2.97	3.25
10	3.19	3.48
25	3.98	3.88
60	4.61	4.11
100	4.78	4.16

Effective permittivity and width
for a 50 Ω impedance

Substrate, $\epsilon_r = 4.2$, $h = 0.38$ mm

Freq (GHz)	W_{50} (mm)	E_{eff}
1	0.75	3.19
3	0.75	3.20
10	0.75	3.24
25	0.77	3.35
60	0.88	3.65
100	1.01	3.88

the too thick substrate acts as a cavity

Therefore, we should reduce the substrate thickness !!

As we know, ADS solves the green functions from the moment method and HFSS solves the Finite Element equations.

If we can define the mesh and ports or even frequency sweep closer to the facts, we can expect the results to be closer to practical situations.

In this case, time domain simulation might be useful.

Thank you !

End of Chapter 8